

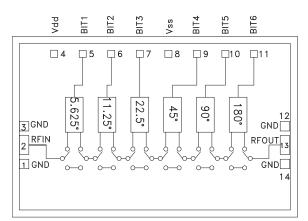
GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 9 - 12.5 GHz

Typical Applications

The HMC642 is ideal for:

- EW Receivers
- Weather & Military Radar
- Satellite Communications
- Beamforming Modules
- Phase Cancellation

Functional Diagram



Features

Low RMS Phase Error: 2.5° Low Insertion Loss: 6.5 dB High Linearity: +41 dBm Positive Control Voltage 360° Coverage, LSB = 5.625° Die Size: 3.25 x 1.9 x 0.1 mm

General Description

The HMC642 is a 6-bit digital phase shifter die which is rated from 9 to 12.5 GHz, providing 360 degrees of phase coverage, with a LSB of 5.625 degrees. The HMC642 features very low RMS phase error of 2.5 degrees and extremely low insertion loss variation of ±0.25 dB across all phase states. This high accuracy phase shifter is controlled with positive control logic of 0/+5V, and is internally matched to 50 Ohms with no external components.

Electrical Specifications, $T_{A} = +25^{\circ} C$, Vee= -5V, Vdd= +5V, Control Voltage = 0/+5V, 50 Ohm System

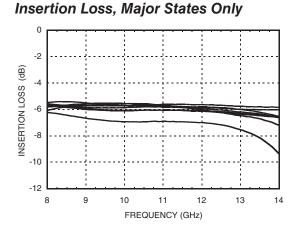
Parameter	Min.	Тур.	Max.	Units
Frequency Range	9		12.5	GHz
Insertion Loss*		6.5	8.5	dB
Input Return Loss*		13		dB
Output Return Loss*		12		dB
Phase Error*		±5	+15 / -8	deg
RMS Phase Error		2.5		deg
Insertion Loss Variation*		±0.25		dB
Input Power for 1 dB Compression		28		dBm
Input Third Order Intercept		41		dBm
Control Voltage Current		<250		μA
Bias Control Current		<12		mA

ote: Major States

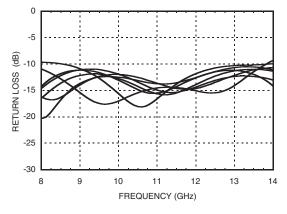
For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824_Phone: 978-250-3343 Fax: 978-250-3373 rder OI-life at www.hittite



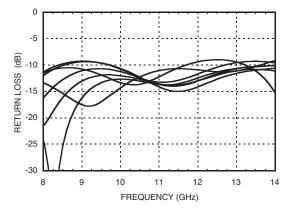
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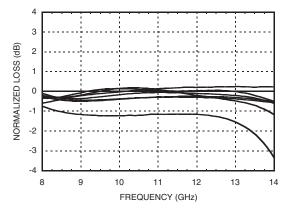
Input Return Loss, Major States Only



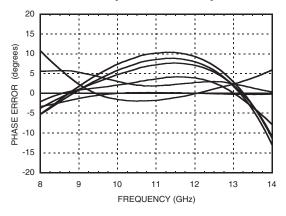
Output Return Loss, Major States Only



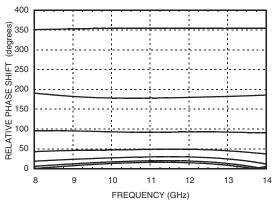




Phase Error, Major States Only



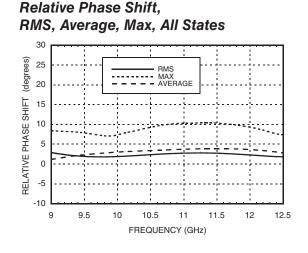
Relative Phase Shift Major States, Including All Bits



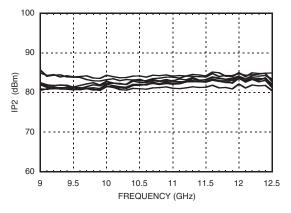
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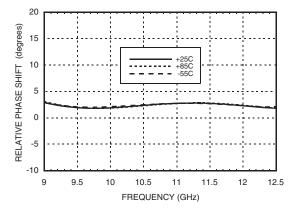
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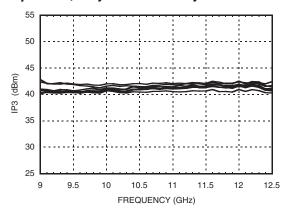
Input IP2, Major States Only



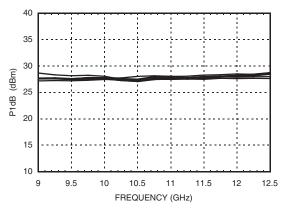
RMS Phase Error vs. Temperature



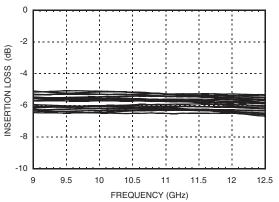
Input IP3, Major States Only



Input P1dB, Major States Only



Insertion Loss vs. Temperature, Major States Only



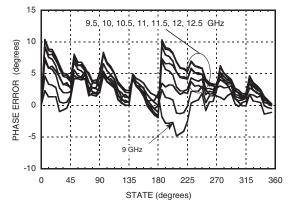
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GaAs MMIC 6-BIT DIGITAL PHASE SHIFTER, 9 - 12.5 GHz

Phase Error vs. State



Truth Table

Control Voltage Input					Phase Shift	
Bit 1	Bit 2	Bit 3	Bit 4	Bit 5	Bit 6	(Degrees) RFIN - RFOUT
0	0	0	0	0	0	Reference*
1	0	0	0	0	0	5.625
0	1	0	0	0	0	11.25
0	0	1	0	0	0	22.5
0	0	0	1	0	0	45.0
0	0	0	0	1	0	90.0
0	0	0	0	0	1	180.0
1	1	1	1	1	1	354.375
Any combination of the above states will provide a phase shift approximately equal to the sum of the bits selected.						
*Reference corresponds to monotonic setting						

Pad Descriptions

Absolute	Maximum	Ratings
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Input Power (RFIN)	30 dBm (T= +85 °C)
Bias Voltage Range (Vdd)	-0.2 to +12V
Bias Voltage Range (Vss)	+0.2 to -12V
Channel Temperature (Tc)	150 °C
Thermal Resistance (channel to die bottom)	60 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Bias Voltage & Current

Vdd	ldd
5.0	5.6mA
Vss	lss
-5.0	5.6mA

Control Voltage

State	Bias Condition	
Low (0)	0 to 0.2 Vdc	
High (1)	Vdd ±0.2 Vdc @ 35 µA Typ.	

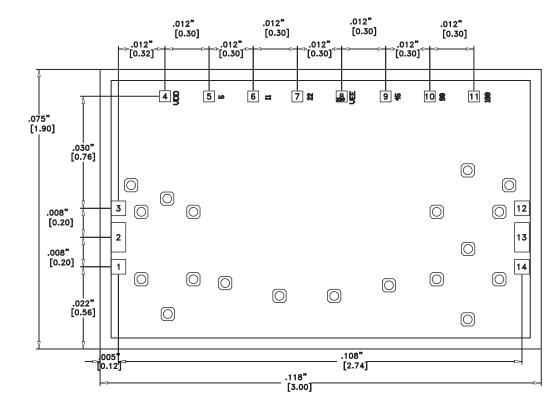
Pad Number	Function	Description	Interface Schematic
1, 3, 12, 14	GND	These pads and die bottom must be connected to RF/DC ground.	
2	RFIN	This port is DC coupled and matched to 50 Ohms.	RFIN O
4	Vdd	Voltage supply.	
5 - 7, 9 - 11	BIT1, BIT2, BIT3, BIT4, BIT5. BIT6	Control Input. See truth table and control voltage tables.	
8	Vss	Voltage supply.	
13	RFOUT	This port is DC coupled and matched to 50 Ohms.	O RFOUT

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Outline Drawing



Die Packaging Information [1]

Standard	Alternate
GP-1 (Gel Pack)	[2]

[1] Refer to the "Packaging Information" section for die packaging dimensions.

[2] For alternate packaging information contact Hittite Microwave Corporation.

NOTES:

- 1. ALL DIMENSIONS IN INCHES (MILLIMETERS)
- 2. DIE THICKNESS IS 0.004
- 3. BACKSIDE METALLIZATION: GOLD
- 4. BACKSIDE METAL IS GROUND
- 5. BOND PADS METALLIZATION: GOLD
- 6. OVERALL DIE SIZE ±0.002

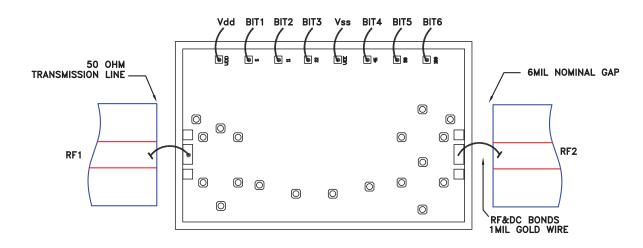
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Assembly Diagram



Handling Precautions

Follow these precautions to avoid permanent damage.

Storage: All bare die are placed in either Waffle or Gel based ESD protective containers, and then sealed in an ESD protective bag for shipment. Once the sealed ESD protective bag has been opened, all die should be stored in a dry nitrogen environment.

Cleanliness: Handle the chips in a clean environment. DO NOT attempt to clean the chip using liquid cleaning systems.

Static Sensitivity: Follow ESD precautions to protect against > ± 250V ESD strikes.

Transients: Suppress instrument and bias supply transients while bias is applied. Use shielded signal and bias cables to minimize inductive pick-up.

General Handling: Handle the chip along the edges with a vacuum collet or with a sharp pair of bent tweezers. The surface of the chip has fragile air bridges and should not be touched with vacuum collet, tweezers, or fingers.

Mounting

The chip is back-metallized and can be die mounted with electrically conductive epoxy. The mounting surface should be clean and flat.

Epoxy Die Attach: Apply a minimum amount of epoxy to the mounting surface so that a thin epoxy fillet is observed around the perimeter of the chip once it is placed into position. Cure epoxy per the manufacturer's schedule.

Wire Bonding

Ball or wedge bond with 0.025mm (1 mil) diameter pure gold wire. Thermosonic wirebonding with a nominal stage temperature of 150 deg. C and a ball bonding force of 40 to 50 grams or wedge bonding force of 18 to 22 grams is recommended. Use the minimum level of ultrasonic energy to achieve reliable wirebonds. Wirebonds should be started on the chip and terminated on the package or substrate. All bonds should be as short as possible <0.31mm (12 mils).

PHASE SHIFTERS - DIGITAL - CHIP 6

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